

HZS-LL Series

Silicon Epitaxial Planar Zener Diode for Hard Knee Low Noise

HITACHI

ADE-208-122A(Z)
Rev 1
Dec. 1996

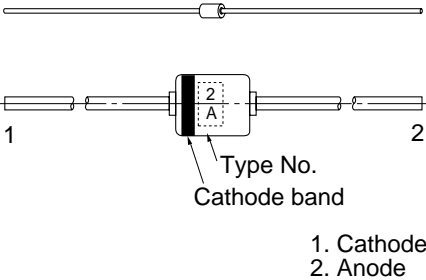
Features

- V_Z - I_Z characteristics are semilogarithmic linear from $I_Z=1\text{nA}$ to 1mA and have sharper breakdown knees in a low current region, and also lower V_Z temperature coefficients .
- Low dynamic impedance and low noise in the low current region (approximately 1/10 lower than the current zeners).
- Suitable for 5mm-pitch high speed automatic insertion.

Ordering Information

Type No.	Mark	Package Code
HZS-LL Series	Type No.	MHD

Outline



HZS-LL Series

Absolute Maximum Ratings (Ta = 25°C)

Item	Symbol	Value	Unit
Power dissipation	Pd	250	mW
Junction temperature	Tj	175	°C
Storage temperature	Tstg	−55 to +175	°C

Electrical Characteristics (Ta = 25°C)

Type	Grade	V _z (V) *1		I _R (nA)		Z _{zt} (Ω)		Z _{zk} (kΩ) *2		ΔV _{z1} (V) *3		ΔV _{z2} (V) *3	
		Min	Max	I _z (mA)	Max	V _R (V)	Max	I _{zt} (mA)	Typ	I _{zk} (μA)	Max	Max	Max
HZS2LL	A	1.6	2.0	0.5	100	0.5	350	0.5	(1.2)	50	0.5	0.6	
	B	1.9	2.3										
	C	2.2	2.6										
HZS3LL	A	2.5	2.9	0.5	100	1.0	360	0.5	(1.2)	50	0.5	0.6	
	B	2.8	3.2										
	C	3.1	3.5										
HZS4LL	A	3.4	3.8	0.5	100	2.0	370	0.5	(1.5)	50	0.5	0.6	
	B	3.7	4.1										
	C	4.0	4.4										
HZS5LL	A	4.3	4.7	0.5	100	3.0	380	0.5	(1.5)	50	0.5	0.6	
	B	4.6	5.0										
	C	4.9	5.3										

Note: 1. Tested with DC.

Note: 2. Reference only.

Note: 3. $\Delta V_{z1} = V_z (I_z = 0.5 \text{ mA}) - V_{z1} (I_z = 0.05 \text{ mA})$ $\Delta V_{z2} = V_{z1} (I_z = 0.05 \text{ mA}) - V_{z2} (I_z = 0.001 \text{ mA})$

Note: 4. Type No. is as follows; HZS2ALL, HZS2BLL, HZS5CLL.

Main Characteristic

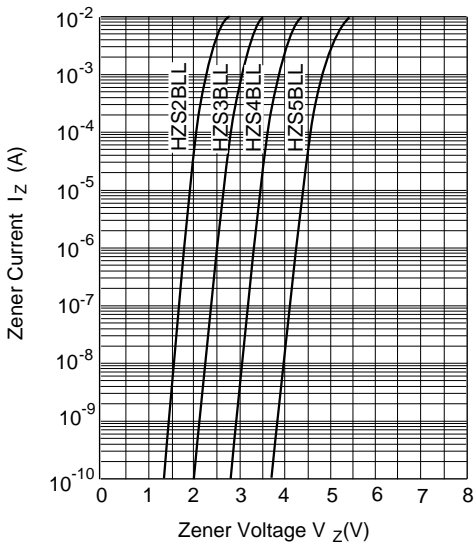


Fig.1 Zener current Vs. Zener voltage

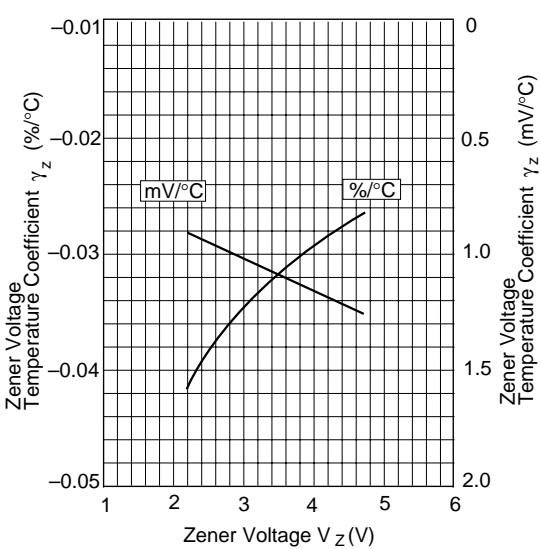


Fig.2 Temperature Coefficient Vs. Zener voltage

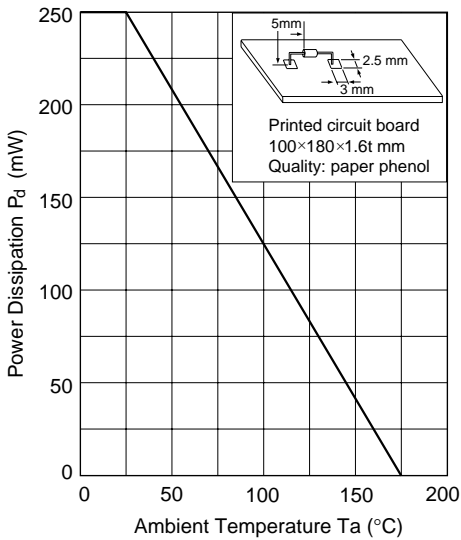
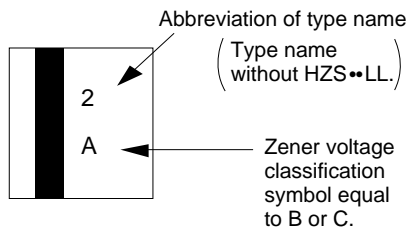
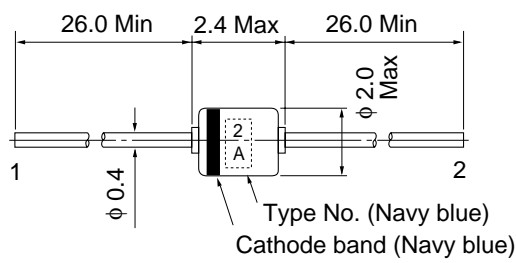


Fig.3 Power Dissipation Vs. Ambient Temperature

Package Dimensions

Unit : mm



Expanded drawing of marking

Hitachi Code	MHD
JEDECCode	DO-34
EIAJCode	-
Weight(g)	0.084

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HITACHI

Hitachi, Ltd.

Semiconductor & Integrated Circuits.
Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan
Tel: Tokyo (03) 3270-2111 Fax: (03) 3270-5109

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For further information write to:

Hitachi Semiconductor (America) Inc. 179 East Tasman Drive, San Jose, CA 95134 Tel: <1> (408) 433-1990 Fax: <1> (408) 433-0223	Hitachi Europe GmbH Electronic components Group Dornacher Straße 3 D-85622 Feldkirchen, Munich Germany Tel: <49> (89) 9 9180-0 Fax: <49> (89) 9 29 30 00 Hitachi Europe Ltd. Electronic Components Group. Whitebrook Park Lower Cookham Road Maidenhead Berkshire SL6 8YA, United Kingdom Tel: <44> (1628) 585000 Fax: <44> (1628) 778322
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Hitachi Asia Pte. Ltd.
16 Collyer Quay #20-00
Hitachi Tower
Singapore 049318
Tel: 535-2100
Fax: 535-1533

Hitachi Asia Ltd.
Taipei Branch Office
3F, Hung Kuo Building, No.167,
Tun-Hwa North Road, Taipei (105)
Tel: <886> (2) 2718-3666
Fax: <886> (2) 2718-8180

Hitachi Asia (Hong Kong) Ltd.
Group III (Electronic Components)
7/F., North Tower, World Finance Centre,
Harbour City, Canton Road, Tsim Sha Tsui,
Kowloon, Hong Kong
Tel: <852> (2) 735 9218
Fax: <852> (2) 730 0281
Telex: 40815 HITEC HX

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